

### ■ Features

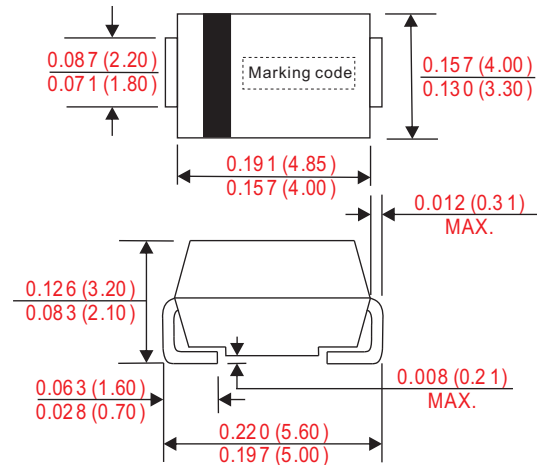
- Electrostatic discharge (ESD) test under IEC6100-4-2 standard >16KV(SK12B~SK16B). standard >10KV(SK110B~SK120B).
- Low profile surface mounted application in order to optimize board space.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Suffix "G" indicates Halogen-free part, ex.SK12BG.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

### ■ Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, DO-214AA / SMB
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Weight : 0.003 ounce, 0.091 gram

### ■ Outline

SMB(DO-214AA)



Dimensions in inches and (millimeters)

### ■ Maximum ratings and electrical characteristics

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	$I_o$			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	$I_{FSM}$			30	A
Reverse current	$V_R = V_{RRM}$ $T_A = 25^\circ\text{C}$	$I_R$			0.5	mA
	$V_R = V_{RRM}$ $T_A = 100^\circ\text{C}$				20	
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	$C_j$		120		pF
Thermal resistance	Junction to ambient	$R_{\theta JA}$		88		°C/W
Storage temperature		$T_{STG}$	-55		+175	°C

Symbol	Marking code	Max. repetitive peak reverse voltage $V_{RRM}$ (V)	Max. RMS voltage $V_{RMS}$ (V)	Max. DC blocking voltage $V_R$ (V)	Max. forward voltage @1A, $T_A = 25^\circ\text{C}$ $V_F$ (V)	Operating temperature $T_J$ (°C)
SK12B	SK12	20	14	20	0.45	-55 ~ +150
SK14B	SK14	40	28	40	0.50	
SK16B	SK16	60	42	60	0.70	
SK110B	SK110	100	70	100	0.81	
SK115B	SK115	150	105	150	0.87	-55 ~ +175
SK120B	SK120	200	140	200	0.90	

■ Rating and characteristic curves

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

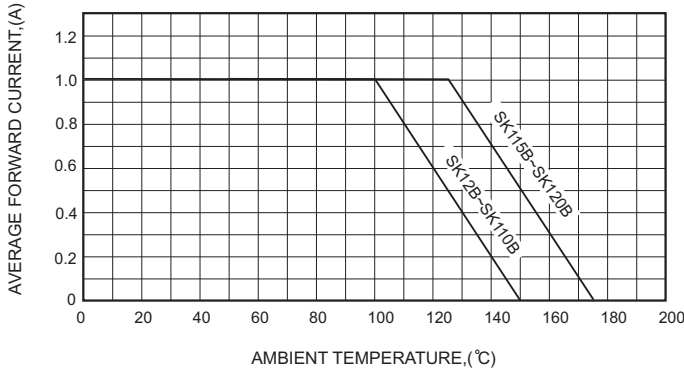


FIG.2-TYPICAL FORWARD CHARACTERISTICS

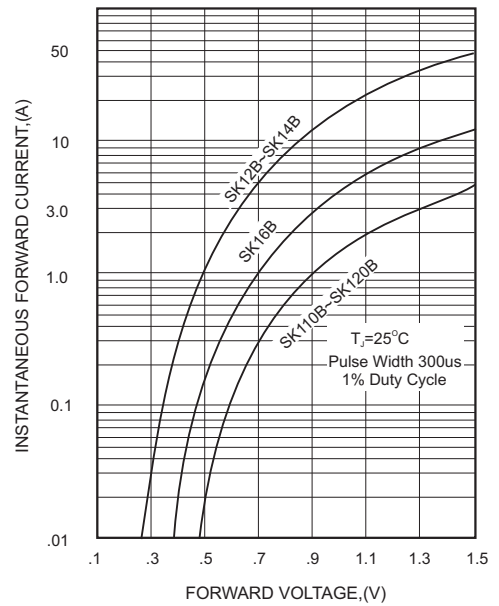


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

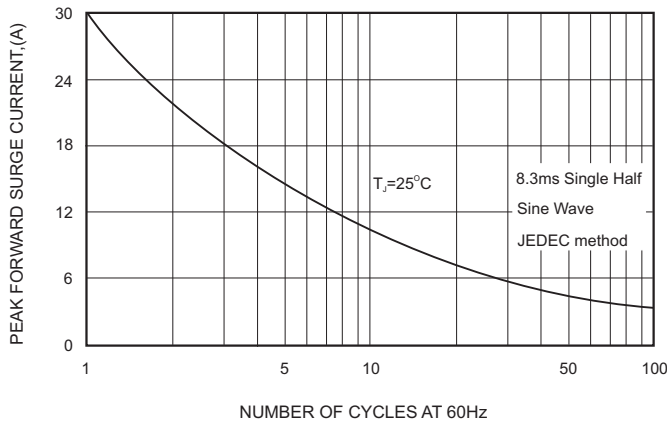


FIG.4-TYPICAL JUNCTION CAPACITANCE

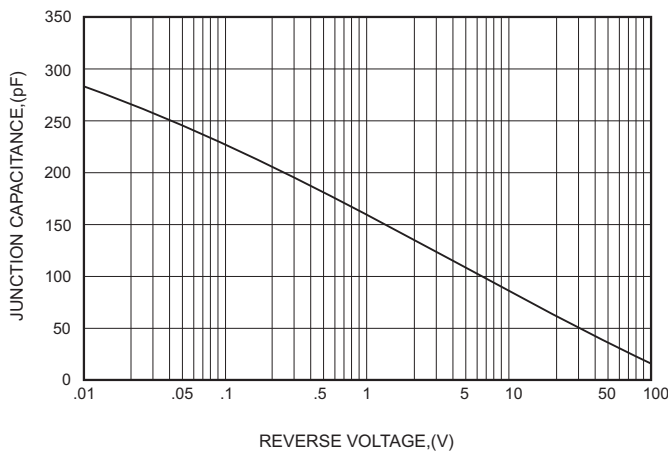
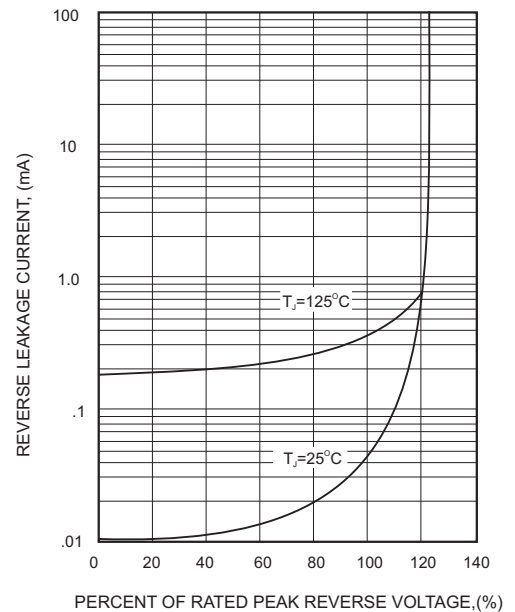
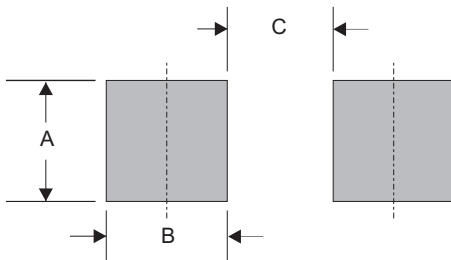


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



■ SMB foot print



A	B	C
0.091 (2.30)	0.098 (2.50)	0.071 (1.80)

Dimensions in inches and (millimeters)

- CITC reserves the right to make changes to this document and its products and specifications at any time without notice.
- Customers should obtain and confirm the latest product information and specifications before final design, purchase or use.
- CITC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does CITC assume any liability for application assistance or customer product design.
- CITC does not warrant or accept any liability with products which are purchased or used for any unintended or unauthorized application.
- No license is granted by implication or otherwise under any intellectual property rights of CITC.
- CITC products are not authorized for use as critical components in life support devices or systems without express written approval of CITC.